2SB1651

Silicon PNP epitaxial planer type

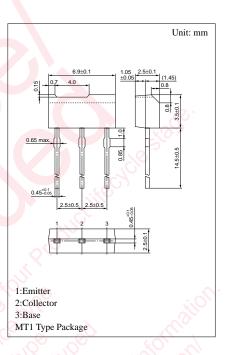
For low-frequency and low-noise amplification

Features

- Low noise voltage NV.
- High foward current transfer ratio h_{FE}.
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	-55	V
Collector to emitter voltage	V _{CEO}	-55	v
Emitter to base voltage	V _{EBO}	-5	V
Peak collector current	I _{CP}	-200	mA
Collector current	I _C	-50	mA
Collector power dissipation	P _C	400	mW
Junction temperature	Tj	<mark>15</mark> 0	°C
Storage temperature	T _{stg}	-55 ~ +150	C C

Absolute Maximum Ratings (Ta=25°C)

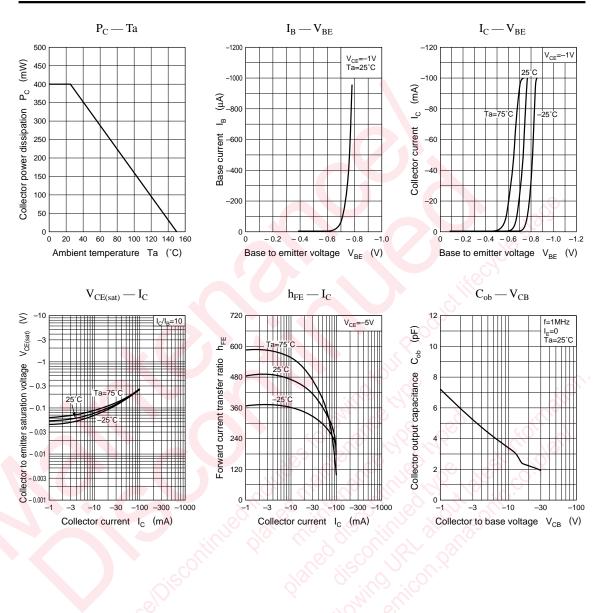


Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I _{CBO}	$V_{CB} = -10V, I_E = 0$			-100	nA
	I _{CEO}	$V_{CE} = -10V, I_B = 0$	K		-1	μΑ
Collector to base voltage	V _{CBO}	$I_{\rm C} = -10 \mu A, I_{\rm E} = 0$	_55			V
Collector to emitter voltage	V _{CEO}	$I_{\rm C} = -2mA, I_{\rm B} = 0$	-55			V
Emitter to base voltage	V _{EBO}	$I_{\rm E} = -10 \mu A, I_{\rm C} = 0$	-5			V
Forward current transfer ratio	h_{FE}^{*1}	$V_{CE} = -5V, I_C = -2mA$	180		700	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{C} = -100 \text{mA}, I_{B} = -10 \text{mA}$			- 0.6	V
Base to emitter voltage	V _{BE}	$V_{CE} = -1V, I_{C} = -100mA$			-1	V
Noise voltage	NV	$V_{CE} = -10V, I_C = -1mA, G_V = 80dB,$ $R_g = 100k\Omega, Function = FLAT$		110		mV
Transition frequency	f _T	$V_{CB} = -5V, I_E = 2mA, f = 200MHz$		150		MHz

*1hFE Rank classification

Rank	R	S	Т
\mathbf{h}_{FE}	180 ~ 360	260 ~ 520	360 ~ 700



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